CONOIDAL CRACK WITH ELLIPTIC BASES, WITHIN CUBIC CRYSTALS, UNDER ARBITRARILY APPLIED LOADINGS - IV. APPLICATION TO ½<110> {111} CROSS-SLIP IN FCC MATERIALS

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ABSTRACT

Assuming the dislocation elliptical in the cross-slip plane at the beginning of the cross-slip process, it is shown that $\langle G \rangle$, a measure of the energy release rate, obtained in *Part I* of this study applies. $\frac{1}{2} <110 > \{111\}$ cross-slip systems, observed in [112] copper single crystals deformed through *stage III* in constant strain rates above room temperature, do correspond to positive local $\langle G \rangle$ maxima. It is also suggested that the same treatment applies to the cross-slip between parallel basal planes in close packed hexagonal (CPH) structures.

Keywords : fracture mechanics, linear elasticity, dislocations, crack extension force, high temperature mechanical twinning, cross-slip.

RÉSUMÉ

Fissure conoïdale à base elliptique dans un cristal cubique sous sollicitations extérieures arbitraires – IV. Application au glissement dévié ½<110> {111} dans les matériaux CFC

En supposant la forme de la dislocation elliptique dans le plan de glissement dévié, au début du processus de déviation, il est montré que $\langle G \rangle$, une mesure du taux de libération d'énergie obtenue dans la *partie I* de cette étude s'applique. Les systèmes de glissement dévié $\frac{1}{2} <110 > \{111\}$, observés dans des monocristaux de cuivre d'axe [112] déformés au *stade III* à des vitesses de déformation constantes au-dessus de la température ambiante, correspondent à des maximas positifs locaux de $\langle G \rangle$. Il est également suggéré que le même traitement s'applique au glissement dévié entre des plans basaux parallèles dans des structures hexagonales compactes (HC).

Mots-clés : *mécanique de la rupture, élasticité linéaire, dislocation, force d'extension de fissure, maclage mécanique à haute température, glissement dévié.*

I - INTRODUCTION

In the same way as in *Part II* and *III* [2, 3], the analysis of *Part I* [1] is applied to $\frac{1}{2} <110 > \{111\}$ cross-slip systems, observed in [112] copper single crystals deformed through *stage III* in constant strain rates above room temperature (present *Part IV*). We refer to the experimental works [4 - 7] and the stereographic projection with centre [112] (*Figure 1*) for the identification of slip systems. Plastic deformation of the specimens begins in *stage II* with the two symmetrical equally stressed slip systems $\frac{1}{2} [011] (1\overline{11})$ and $\frac{1}{2} [101] (\overline{111})$.



Figure 1 : *Stereographic projection with centre* [112] *for the identification of slip systems*

The hardening rate ($\theta = d\tau / d\gamma$; τ and γ , shear stress and strain) in *stage II*, θ_{II} , is constant with stress τ . At a stress level called τ_{III} begins the deformation stage *III* where θ_{III} is decreasing with stress [4 – 6]. Abundant cross-slips occur on the deviation plane (111) and these are due to screws ½ [011] and ½ [101] gliding initially on (111) and (111), respectively [4, 7]. In this *part IV* and *Section* 2, the methodology for the use of the analysis in [1] is described. In *Section* 3, results are displayed corresponding to cross-slips. Section 4 and 5 concern discussion and conclusion, respectively.

II - METHODOLOGY

Figure 2 shows the conoidal crack geometry under load that has been used in [1] to calculate the associated crack extension force G per unit length of the crack front.



Figure 2 : Elliptical base (elevation $x_2 = OO' \equiv h$) of the conoidal crack with semiaxes ρ_1 and ρ_2 along x_1 and x_3 . The running point P_D [1] along the base and angular parameters θ_0 and ϕ_0 that connect x_j and \vec{x}_j are illustrated. Angle θ is introduced by the relation $\tan \theta = OO'/\rho_1$. The medium suffers uniformly applied tension σ_{22}^a in the vertical x_2 - direction and shears σ_{21}^a and σ_{23}^a (parallel to the horizontal x_1x_3 - plane) in the x_1 and x_3 directions.

Induced normal Poisson's stresses $-\nu_A(j)\sigma_{22}^a$ along x_1 (j=1) and x_3 (j=3) are included. The crack nuclei are arbitrarily oriented with attached Cartesian (O; x_j); $O x_2$ is a symmetrical axis. In x_1x_3 – planes, the bases are elliptical with semiaxes ρ_1 and ρ_2 along x_1 and x_3 such that $a_r = \rho_1 / \rho_2 = \text{constant}$ about any elevation $x_2 = OO' \equiv h$ along $O x_2$. The angle ϕ is between $O' x_3$ and $O'P_D$ as shown in *Figure 2*. Angle θ is measured in $O x_1 x_2$ between $P_D (\phi = \pi/2) O'$ and $P_D (\phi = \pi/2) O$ where $P_D (\phi = \pi/2)$ has elevation $x_2 = h$ from $O x_1 x_3$; its alternate interior angle is shown in *Figure 2*. Additional angular parameters θ_0 and ϕ_0 (Euler's angles) are introduced that connect \vec{x}_j to \vec{x}_j . We consider average $\langle G \rangle$.



Figure 3 : Configuration (at an arbitrary time t) of the screw dislocation 1/2[011] during the cross-slip process. The shape is assumed elliptical in $(11\overline{1})$ and the parts in $(1\overline{1}1)$ are hatched

obtained in the first part of this study (see relation (34) of [1]) and present below graphical plots of its normalized value $\langle \tilde{G}_r \rangle$ defined as

$$< \tilde{G}_{r} > = < G > /G_{Cs}^{I} = < \tilde{G}_{r} > (\theta, \theta_{0}, \phi_{0}, M_{12}, M_{13}, a_{r}, C_{nm}) ,$$

$$G_{Cs}^{I} = \frac{2^{4} \alpha_{0}^{2}}{3\pi^{2} C_{44}} (K_{I}^{0})^{2} ;$$

$$(1)$$

where $K_1^0 = \sigma_{22}^a \sqrt{\pi\Delta}$, $M_{12} = \sigma_{21}^a / \sigma_{22}^a$ and $M_{13} = \sigma_{23}^a / \sigma_{22}^a$; Δ is the separation of the partial dislocations. The applied stresses are viewed as effective stresses acting on the dislocations in the medium. The room temperature average values $C_{11} = 1.691$, $C_{12} = 1.222$ and $C_{44} = 0.7542$ in units of $[10^{11}N / m^2]$ for copper have been used (see *Table* 2 in [8]). *Figure* 2 is used to specify a plane of crossslip (S). x_2 is vertical, parallel to the applied tension, x_3 is then determined as the intersection between (S) and the laboratory horizontal plane (x_2) = Ox_1x_3 allowing x_1 to be known. For definiteness, x_2 is fixed to [112] and we seek possible cross-slip systems under such conditions. Then graphical plots of $\langle \tilde{G}_r \rangle$ as a function of ϕ_0 are displayed. The cross-slip propagation directions [U] in (S) are those associated to positive local maxima. We take (S) = (111)

[4, 7] : using *Figure 1* and 2 and indicating the directions only, we have

$$\theta_0 = \pi/2, x_2 = [112], x_3 = [110], x_1 = [111], x_2 = [111]$$
 (2)

Figure 3 displays the configuration (at an arbitrary time t) of the screw dislocation $\frac{1}{2}$ [011] during the cross-slip process. The shape is assumed elliptical in $(11\overline{1})$ and the parts in $(1\overline{1}1)$ are hatched. As the ellipse expands in $(11\overline{1})$, the configurations in $(1\overline{1}1)$ remain unchanged; consequently, these latter contribute non-additional value to $\langle G \rangle \langle d \langle G \rangle = 0 \rangle$ there. Hence, $\langle G \rangle$ value is carried by the elliptical shape in $(11\overline{1})$. The quantity $\langle G \rangle$ (see expression (34) in [1]) applies. Positive local maxima of $\langle \tilde{G}_r \rangle$ correspond to equilibrium states of the cross-slip. The loadings are along x_i as indicated (*Figure 3*). $a_r = a_1 / a_2$, where a_1 and a_2 are the semiaxes along $x'_1 = [\overline{1}10]$ and $x'_3 = [\overline{1}\overline{12}]$, respectively. In the stationary configuration, we take $2a_2 = \Delta$ the separation of partials (1). The resolved shear stress τ_{III} at the beginning of stage III has been found thermally activated, satisfying an Arrhenius law temperature T dependence [4-6]. This can be included in the analysis in a similar way as for τ_V [2] the stress at the beginning of twinning.

III - RESULTS

Figure 4 is a plot of $\langle \tilde{G}_r \rangle$ (1) for $(S) = (11\overline{1})$ (2) as a function of ϕ_0 . Positive maxima of $\langle \tilde{G}_r \rangle$ are at $\phi_0 = \pi/2$ and π approximately (visual inspection). The former corresponds to the cross-slip system $[011](11\overline{1})$ ($\phi_0 = \pi/2$). The second may be other mechanisms ($[\overline{112}](11\overline{1})$ twinning and fracture, for instance); these are observed at higher stress levels as compared to τ_{III} under similar temperatures. *Figure 5* shows $\langle \tilde{G}_r \rangle$ (1) for the cross-slip system $[011](11\overline{1})$ ($\theta_0 = \pi/2$, $\phi_0 = \pi/2$) as a function of a_r . Visual inspection shows non-negative values of $\langle \tilde{G}_r \rangle$ close to zero, from $a_r \cong 0$ up to $a_r \cong 1.5$. Above 1.5, $\langle \tilde{G}_r \rangle$ is clearly negative. A maximum positive $\langle \tilde{G}_r \rangle$ value is expected about $a_r = 1$ which would be the value of a_r at the equilibrium state. $a_1 \cong a_2 \cong \Delta/2$ is expected in the equilibrium configuration of the cross-slip mechanism (*Figure 3*). A further expansion of the loop from that position

would correspond to $d < \tilde{G}_r >= 0$. Under such conditions, the cross-slip process is completed allowing motion of the perfect dislocation in the cross-slip plane. We stress that at the beginning of the cross-slip process (*Figure 3*), θ is expected to be close to $\pi/2$; this is appreciated using *Figure 2*.



Figure 4 : $<\tilde{G}_r > (1)$ as a function of ϕ_0 for $\theta = \pi / 2$ and $\theta_0 = \pi / 2$. This corresponds to the cross-slip system $[011](11\overline{1}) (\phi_0 = \pi / 2)$. $M_{12} = M_{13} = 10^{-4}$, $v_A(1) = v_A(3) = 1/3$, $a_r = 3 / 4$, copper

IV - DISCUSSION

Assuming the dislocation elliptical in the cross-slip plane at the beginning (*Figure 3*), $\langle G \rangle$ obtained in [1] applies. Fixing $\theta = \pi/2$ means maintaining a_1 close to zero ($a_1 \Box 0$) from the definition of θ [1]: we have $\tan \theta = OO'/a_1$ (*Figure 2*). At $\phi_0 = \pi/2$ (*Figure 3*), the tensile stress along x'_3 is $\sigma''_{33} = \sigma^a_{22}$ allowing a_2 to increase. Under such conditions, a_2 can be larger than a_1 , meaning that $a_r = a_1/a_2 < 1$. $\langle \tilde{G}_r \rangle$ values in *Figure 4* conform to these conditions; positive local maximum of $\langle \tilde{G}_r \rangle$ is at $\phi_0 = \pi/2$. This is the equilibrium state $d < \tilde{G}_r >= 0$ of the cross-slip event. Another observed maximum is at $\phi_0 = \pi$. This would correspond to other mechanisms such as twinning and fracture. We can comment about the positive minimum of $\langle \tilde{G}_r \rangle$



Figure 5: $<\tilde{G}_r > (1)$ as a function of a_r for $\theta = \pi / 2$ and the cross-slip system [011](111) ($\theta_0 = \phi_0 = \pi/2$). $M_{12} = M_{13} = 10^{-4}$, $v_A(1) = v_A(3) = 1/3$, $a_r = 3 / 4$, copper

observed at $\phi_0 = 0$ (*Figure 4*) : using *Figure 3*, the tension along x_1 is $\sigma_{11}^{A} = \sigma_{22}^{a}$ allowing a_1 to increase, but this is hindered by the condition $\theta = \pi/2$ ($a_1 \Box 0$); Poisson stress is compressive and reads $\sigma_{33}^{A} = -v_A(3)\sigma_{22}^{a}$ hindering also the increase of a_2 . Under such conditions $\phi_0 = 0$ is not favoured in *Figure 4*. In summary, the analysis of *Part I* [1] predicts the observed crossslip system [011](111) of the face-centred-cubic (FCC) structure using the configuration of the screw dislocation, at an arbitrary time *t*, given by *Figure 3*. Earliest works [9 - 12] on cross-slip have used configuration like *Figure 3*.



Figure 6 : Configuration, under load, of the screw dislocation in the crossslip process between basal planes of CPH structure

We next make a discussion on cross-slip in close packed hexagonal (CPH) structure. A configuration under load, at a given time t, of the cross-slip event between basal planes is depicted in *Figure 6*. The dissociation of the dislocation occurs in parallel planes. It is again assumed an elliptical shape for the dislocation on the cross-slip plane at the beginning of the process. The configuration out of the deviation plane remains unchanged during an increase of time dt; this means that d < G >= 0 there; hence the change in <G > is entirely carried by the elliptical dislocation. This means that the treatment of *Part I* [1] applies for CPH structures. *Figure 6* is considered in previous works [13, 14].

V - CONCLUSION

Assuming the shape of the dislocation elliptical (*Figure 3*) in the cross-slip plane at the beginning of the cross-slip process, it is shown that $\langle G \rangle$, a measure of the energy release rate, obtained in *Part I* [1] of this study applies. $\frac{1}{2} \langle 110 \rangle$ {111} cross-slip systems, observed in [112] copper single crystals deformed through *stage III* in constant strain rates above room temperature, do correspond to positive local $\langle G \rangle$ maxima. It is also suggested that the same treatment applies to the cross-slip between parallel basal planes in close packed hexagonal (CPH) structures.

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